Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in an MLPAK33-WF (SOT8002-3) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic-level compatible
- Very fast switching
- · Trench MOSFET technology
- Side-wettable flanks for optical solder inspection
- Thermally efficient package in a small form factor (3.3 mm x 3.3 mm footprint)
- · AEC-Q101 qualified

3. Applications

- Reverse polarity protection
- · High-speed line driver
- · High-side load switch
- · Relay driver

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	-80	V
V_{GS}	gate-source voltage	T _j = 25 °C	[1]	-20	-	20	V
I _D	drain current	V _{GS} = -10 V; T _{mb} = 25 °C		-	-	-16	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C		-	-	56	W
Static characte	ristics						
R _{DSon}	drain-source on-state resistance	V_{GS} = -10 V; I_D = -2.9 A; T_j = 25 °C		-	81	100	mΩ

[1] See application note AN90001.



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	1 2 3 4	
2	S	source		D
3	S	source		
4	G	gate]	_G (F)
5	D	drain		
6	D	drain		S
7	D	drain	8 7 6 5	017aaa094
8	D	drain	MLPAK33 (SOT8002-3)	

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BUK6Q100-80P		plastic thermal enhanced surface mounted package with side-wettable flanks (SWF); mini leads; 8 terminals;pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-3			

7. Marking

Table 4. Marking codes

Type number	Marking code
BUK6Q100-80P	NXG

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-80	V
V _{GS}	gate-source voltage	T _j = 25 °C	[1]	-20	20	V
I _D	drain current	V _{GS} = -10 V; T _{mb} = 25 °C		-	-16	Α
		V _{GS} = -10 V; T _{mb} = 100 °C		-	-11	Α
I _{DM}	peak drain current	single pulse; t _p ≤ 10 µs; T _{mb} = 25 °C		-	-64	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C		-	56	W
T _j	junction temperature			-55	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C
Source-drain	diode					
Is	source current	T _{mb} = 25 °C		-	-16	Α
I _{SM}	peak source current	T_{mb} = 25 °C; single pulse; $t_p \le 10 \mu s$		-	-64	Α
Avalanche rug	ggedness		'			
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$V_{sup} \le -80 \text{ V}; V_{GS} = -10 \text{ V}; T_{j(init)} = 25 \text{ °C}; R_{GS} = 50 \Omega; I_D = -22.8 \text{ A}; unclamped$	[2] [3]	-	49	mJ
I _{AS}	non-repetitive avalanche current	$T_{j(init)} = 25 ^{\circ}C$	[4]	-	-22.8	А

- [1] See application note AN90001.
- [2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
- [3] Refer to application note AN10273 for further information.
- [4] Protected by 100% test.

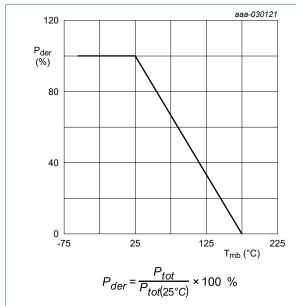


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

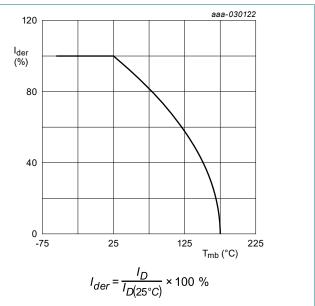


Fig. 2. Normalized continuous drain current as a function of mounting base temperature

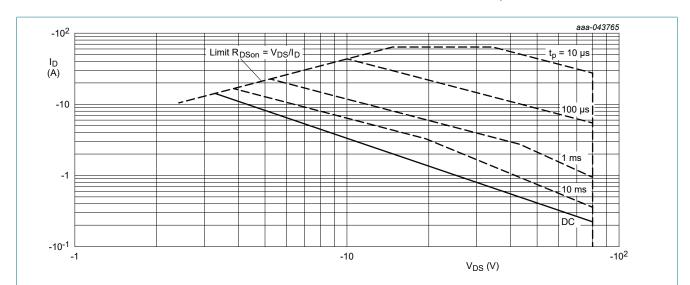


Fig. 3. Safe operating area; junction to mounting base; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	60	80	K/W
R _{th(j-mb)}	thermal resistance from junction to mounting base			-	1.8	2.7	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².

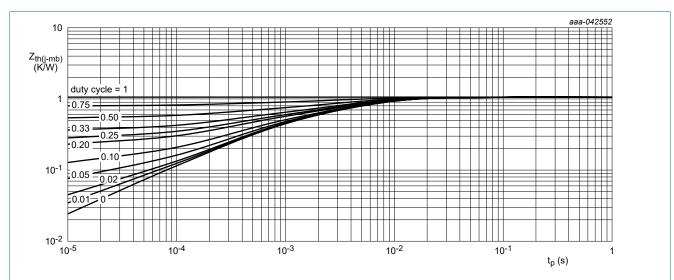


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 μ A; V_{GS} = 0 V; T_j = 25 °C	-80	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = -1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	-1.4	-2	-2.7	V
I _{DSS} drain leakage curre	drain leakage current	V _{DS} = -80 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μΑ
		V _{DS} = -80 V; V _{GS} = 0 V; T _j = 125 °C	-	-	-20	μΑ
I _{GSS}	gate leakage current	V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
		V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state	V_{GS} = -10 V; I_D = -2.9 A; T_j = 25 °C	-	81	100	mΩ
resistance	resistance	V _{GS} = -10 V; I _D = -2.9 A; T _j = 175 °C	-	180	230	mΩ
	V_{GS} = -4.5 V; I_D = -2.5 A; T_j = 25 °C	-	93	137	mΩ	
g _{fs}	forward transconductance	$V_{DS} = -5 \text{ V}; I_D = -2.9 \text{ A}; T_j = 25 \text{ °C}$	-	12.9	-	S
R_G	gate resistance	f = 1 MHz	-	11	-	Ω
Dynamic ch	aracteristics		,			
Q _{G(tot)}	total gate charge	V _{DS} = -40 V; I _D = -2.9 A; V _{GS} = -10 V;	-	21.5	32	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	3.4	-	nC
Q_{GD}	gate-drain charge		-	5	-	nC
C _{iss}	input capacitance	V _{DS} = -40 V; f = 1 MHz; V _{GS} = 0 V;	-	1090	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	72	-	pF
C _{rss}	reverse transfer capacitance		-	39	-	pF
d(on)	turn-on delay time	V _{DS} = -40 V; I _D = -2.9 A; V _{GS} = -10 V;	-	3	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	5	-	ns
t _{d(off)}	turn-off delay time	1	-	41	-	ns
t _f	fall time		-	173	-	ns
Source-drai	in diode					
V_{SD}	source-drain voltage	I _S = -1.9 A; V _{GS} = 0 V; T _j = 25 °C	-	-0.7	-1.2	V
t _{rr}	reverse recovery time	$I_S = -1.9 \text{ A}; \text{ d}I_S/\text{d}t = 100 \text{ A/}\mu\text{s};$	-	25	-	ns
Q _r	recovered charge	$V_{GS} = 0 \text{ V}; V_{DS} = -40 \text{ V}; T_j = 25 \text{ °C}$	-	27	-	nC

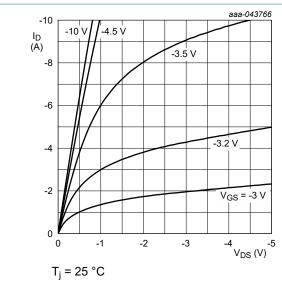


Fig. 5. Output characteristics: drain current as a function of drain-source voltage; typical values

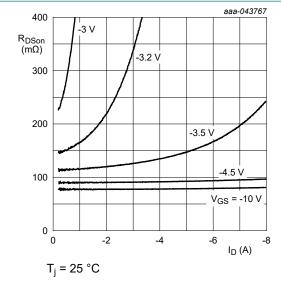


Fig. 7. Drain-source on-state resistance as a function of drain current; typical values

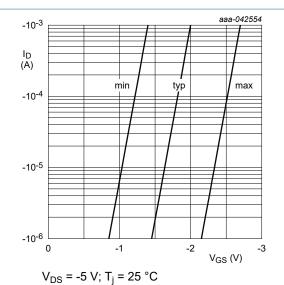


Fig. 6. Sub-threshold drain current as a function of gate-source voltage

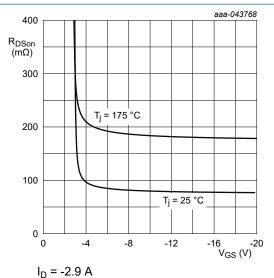


Fig. 8. Drain-source on-state resistance as a function of gate-source voltage; typical values

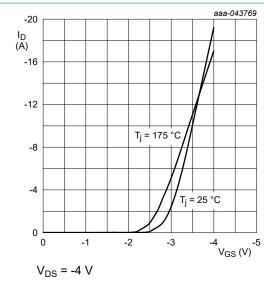


Fig. 9. Transfer characteristics: drain current as a function of gate-source voltage; typical values

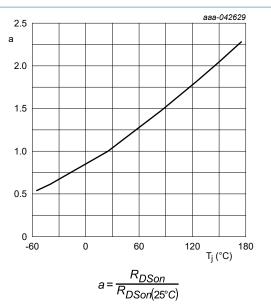


Fig. 10. Normalized drain-source on-state resistance as a function of junction temperature; typical values

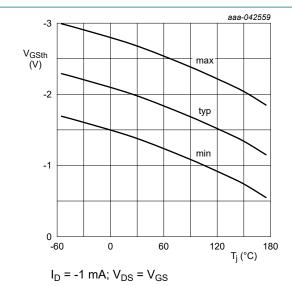
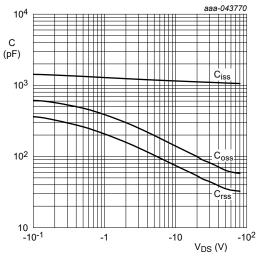


Fig. 11. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$

Fig. 12. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

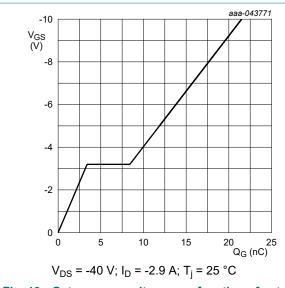


Fig. 13. Gate-source voltage as a function of gate charge; typical values

 $V_{GS} = 0 V$

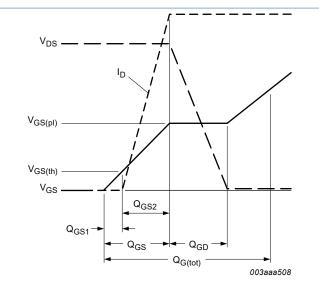


Fig. 14. Gate charge waveform definitions

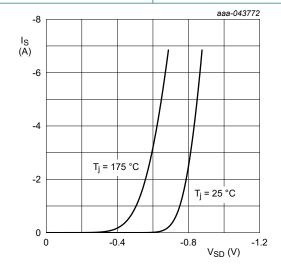
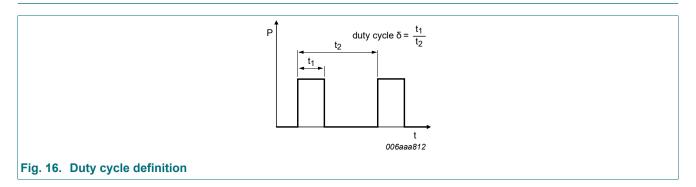


Fig. 15. Source current as a function of source-drain voltage; typical values

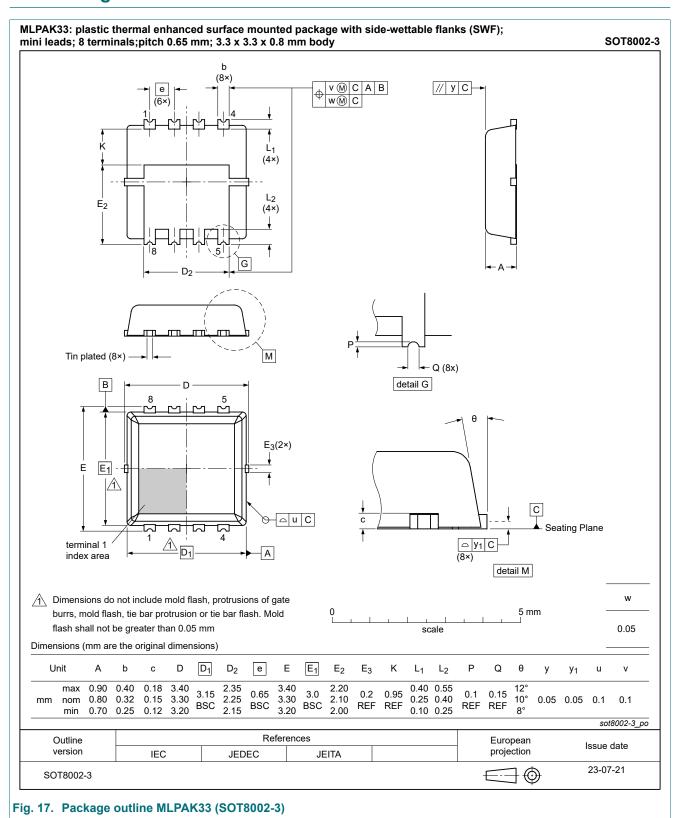
11. Test information



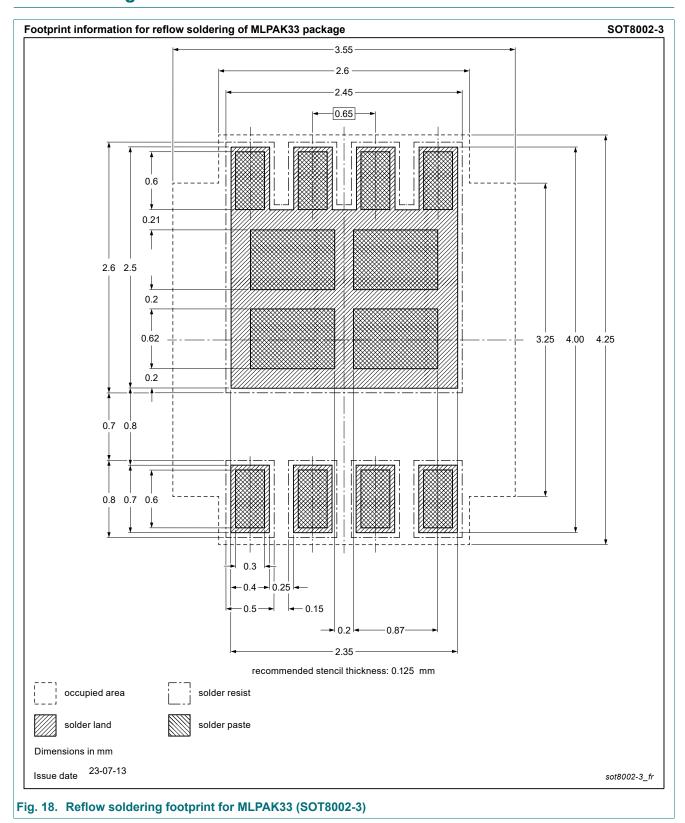
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



13. Soldering



14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BUK6Q100-80P v.1	20251001	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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